

HK SERIES TRANSISTORS

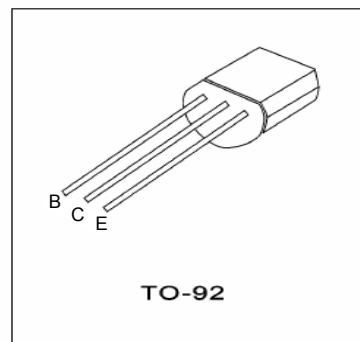
HK 13001

- **FEATURES:** ① HIGH VOLTAGE CAPABILITY ② HIGH SPEED SWITCHING ③ WIDE SOA
 ● **APPLICATION:** ① FLUORESCENT LAMP ② ELECTRONIC BALLAST

● Absolute Maximum Ratings ($T_c=25^\circ\text{C}$)

PARAMETER	SYMBOL	VALUE	UNIT
Collector - Base Voltage	V_{CB0}	500	V
Collector - Emitter Voltage	V_{CE0}	400	V
Emitter - Base Voltage	V_{EB0}	9	V
Collector Current	I_C	0.3	A
Total Power Dissipation	P_c	7	W
Junction Temperature	T_j	150	$^\circ\text{C}$
Storage Temperature	T_{stg}	- 65-150	$^\circ\text{C}$

TO-92 NPN



● Electronic Characteristics ($T_c=25^\circ\text{C}$)

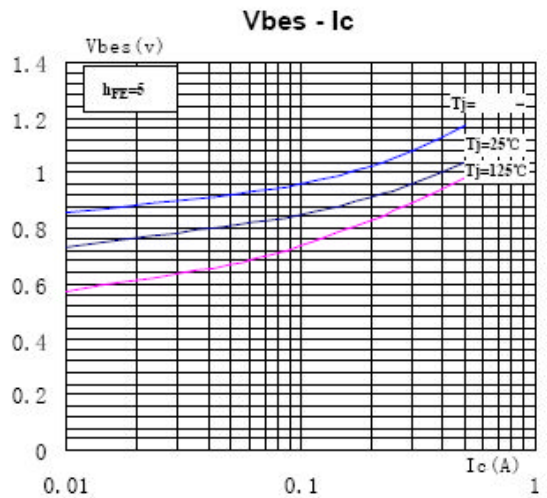
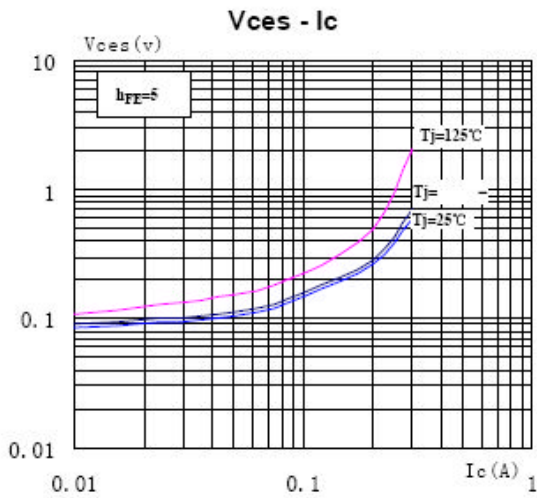
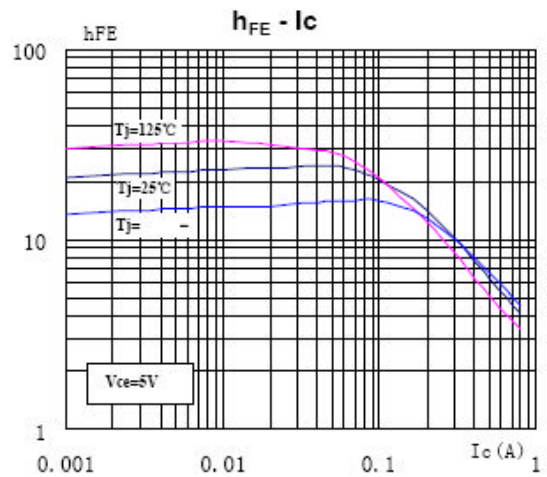
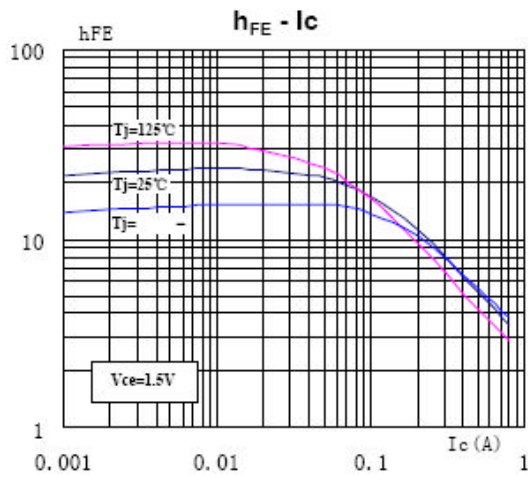
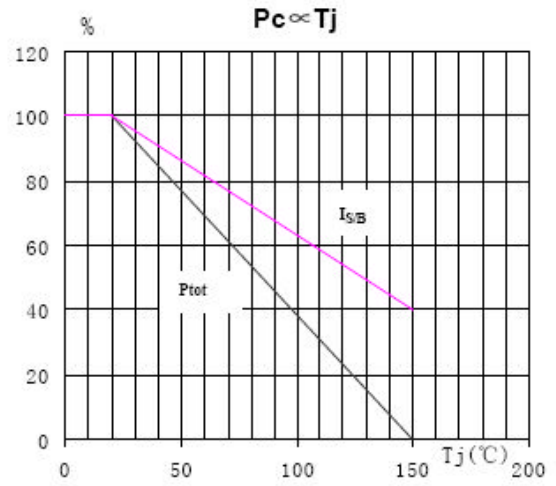
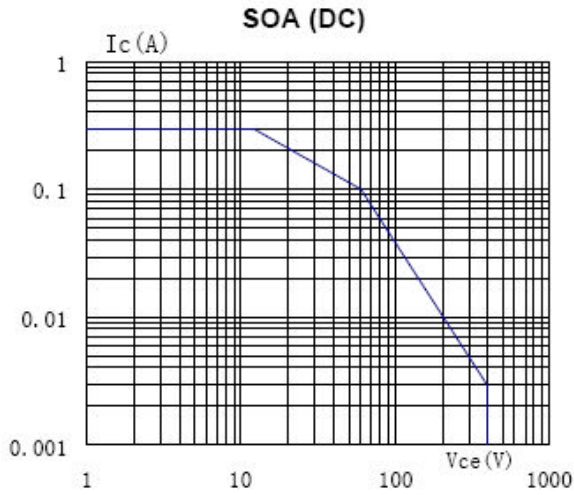
CHARACTERISTICS	SYMBOL	TEST CONDITION	MIN	MAX	UNIT
Collector - Base Cutoff Current	I_{CB0}	$V_{CB} = 500\text{V}$		100	μA
Collector - Emitter Cutoff Current	I_{CE0}	$V_{CE} = 400\text{V}$		250	μA
Collector - Emitter Voltage	V_{CE0}	$I_C = 10\text{mA}$ $I_B = 0$	400		V
Emitter - Base Voltage	V_{EB0}	$I_E = 1\text{mA}$ $I_C = 0$	9		V
Collector - Emitter Saturation Voltage	V_{cesat}	$I_C = 0.05\text{A}$ $I_B = 0.01\text{A}$		0.4	V
		$I_C = 200\text{mA}$ $I_B = 50\text{mA}$		0.8	V
Base - Emitter Saturation Voltage	V_{besat}	$I_C = 50\text{mA}$ $I_B = 10\text{mA}$		1.1	V
DC Current Gain	HFE	$V_{CE} = 5\text{V}$ $I_C = 1\text{mA}$	7		
		$V_{CE} = 20\text{V}$ $I_C = 20\text{mA}$	10	40	
		$V_{CE} = 5\text{V}$ $I_C = 250\text{mA}$	5		
Storage Time	T_s	$V_{CC} = 5\text{V}$	0.5	2.5	μS
Falling Time	T_f	$I_C = 0.1\text{A}$		0.8	μS

● CLASSIFICATION OF HFE AND T_s

HFE	10 - 15	15 - 20	20 - 25	25 - 30
T_s	0.5 - 1.0	1.0 - 1.5	1.5 - 2.0	2.0 - 2.5

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TO-92 MECHANICAL DATA

SYMBOL	Min	Nom	Max
A	4.3		5.3
b	0.3		
c	0.3		
D	4.3		5.2
d	1.0		1.7
E	3.2		4.2
e		2.54	
e1		1.27	
L	12.7		
L1			2.0

